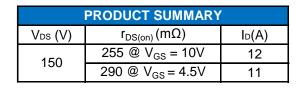
# N-Channel 150-V (D-S) MOSFET

### **Key Features:**

- Low r<sub>DS(on)</sub> trench technology
- · Low thermal impedance
- · Fast switching speed

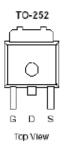
### **Typical Applications:**

- PoE Power Sourcing Equipment
- PoE Powered Devices
- Telecom DC/DC converters
- · White LED boost converters









ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^{\circ}C$ UNLESS OTHERWISE NOTED)								
Parameter		Symbol	Limit	Units				
Drain-Source Voltage		V <sub>DS</sub>	150	V				
Gate-Source Voltage	Source Voltage			v				
Continuous Drain Current	T <sub>C</sub> =25°C	I <sub>D</sub>	10	А				
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	50	А				
Continuous Source Current (Diode Conduction)		ا <sub>S</sub>	45	А				
Power Dissipation	T <sub>C</sub> =25°C	PD	50	W				
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to 175	°C				

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Maximum	Units		
Maximum Junction-to-Ambient <sup>a</sup>	$R_{\thetaJA}$	50	°C/W		
Maximum Junction-to-Case	$R_{ extsf{ heta}JC}$	3	0/11		

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

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# **Electrical Characteristics**

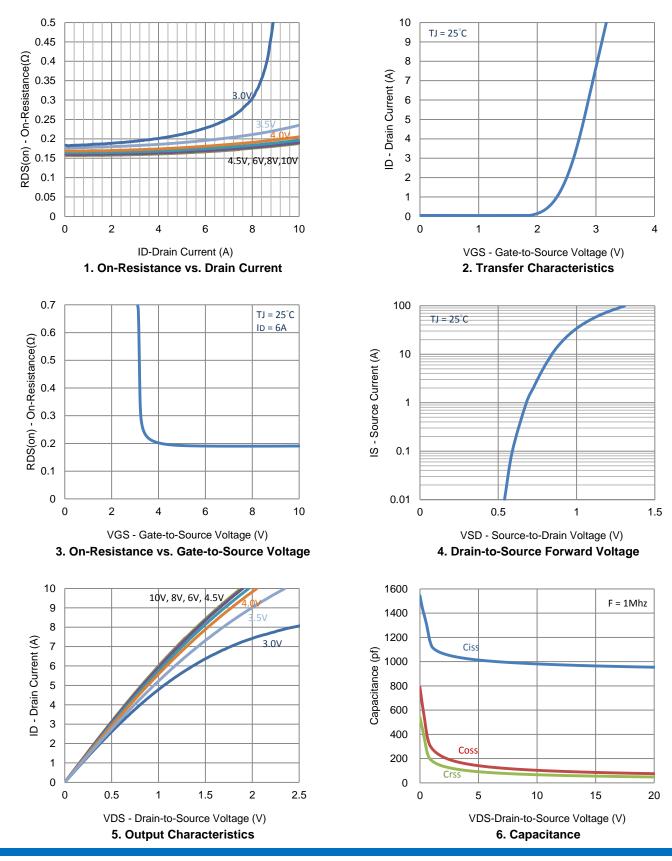
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit		
Static								
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \text{ uA}$	1			V		
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = 20 V$			±10	uA		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 120 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			1	uA		
		$V_{DS} = 120 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25			
On-State Drain Current	I <sub>D(on)</sub>	$V_{DS} = 5 V, V_{GS} = 10 V$	34			Α		
Drain-Source On-Resistance	r	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 6 \text{ A}$			255	mΩ		
	r <sub>DS(on)</sub>	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 5 \text{ A}$			290			
Forward Transconductance	<b>g</b> <sub>fs</sub>	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 6 \text{ A}$		20		S		
Diode Forward Voltage	$V_{SD}$	$I_{S} = 25 \text{ A}, V_{GS} = 0 \text{ V}$		0.95		V		
Dynamic								
Total Gate Charge	Qg	$V_{DS} = 75 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 6 \text{ A}$		16.7		nC		
Gate-Source Charge	$Q_gs$			3.5				
Gate-Drain Charge	$Q_{gd}$			9.3				
Turn-On Delay Time	t <sub>d(on)</sub>	$V_{DD}$ = 75 V, R <sub>L</sub> = 12.5 Ω , I <sub>D</sub> = 6 A, V <sub>GEN</sub> = 10 V, R <sub>GEN</sub> = 6 Ω		11				
Rise Time	t <sub>r</sub>			34		ns		
Turn-Off Delay Time	t <sub>d(off)</sub>			46				
Fall Time	t <sub>f</sub>			77				
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0 V, f =1Mhz		965		pF		
Output Capacitance	C <sub>oss</sub>			86				
Reverse Transfer Capacitance	C <sub>rss</sub>			55				

#### Notes

- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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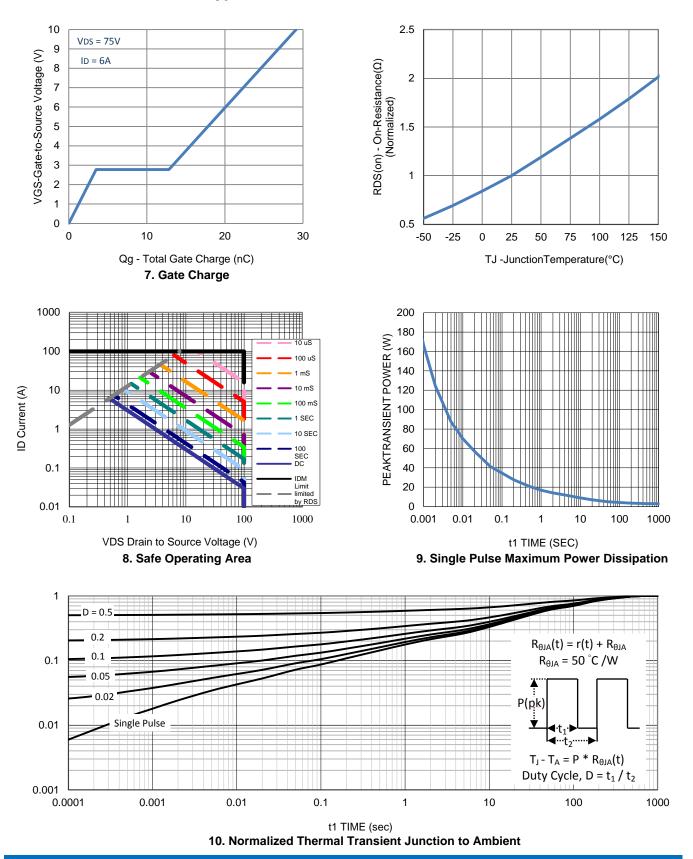


**Typical Electrical Characteristics** 

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Publication Order Number: DS-AM20N15-250D-1A



### **Typical Electrical Characteristics**

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REQMIS

MA)

6.73

1.77

1.27

1.01

6.22

10.40

0.88

1.14

5.46

2.38 0.127

0.60

0.58

\_\_\_

10°

NDM

6.60

1.52

0.508 BSC

\_\_\_

\_\_\_

6.10

10.00 0.76

0.84

2.30

0.50

0.50

\_\_\_

5.34 2.286 B

2.743 REF

6.40

1.40

0.89

\_\_\_

6.00

9.40

0.64 0.7

5.21

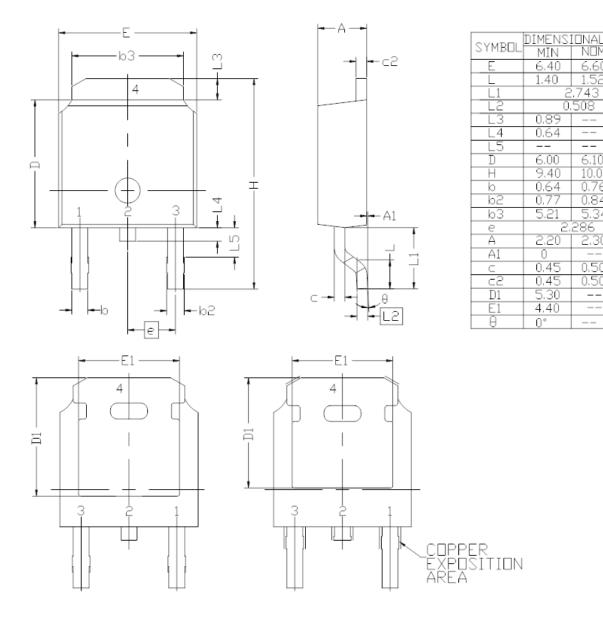
2.20

0

0.45

5.30

# **Package Information**



#### Note:

- All Dimension Are In mm. 1.
- Package Body Sizes Exclude Mold Flash, Protrusion Or Gate Burrs. Mold Flash, Protrusion Or Gate Burrs Shall Not 2. Exceed 0.10 mm Per Side.
- Package Body Sizes Determined At The Outermost Extremes Of The Plastic Body Exclusive Of Mold Flash, Gate 3. Burrs And Interlead Flash, But Including Any Mismatch Between The Top And Bottom Of The Plastic Body.

# **Ordering Information**

- AM20N15-250D-T1-XX
  - A:
  - M:
  - 20N15-250:
  - D:
  - T1:
  - XX:

Analog Power

- MOSFET
- Part number, N-Channel
- TO-252
- Tape & reel
- Blank: Standard
- PF: Leadfree